

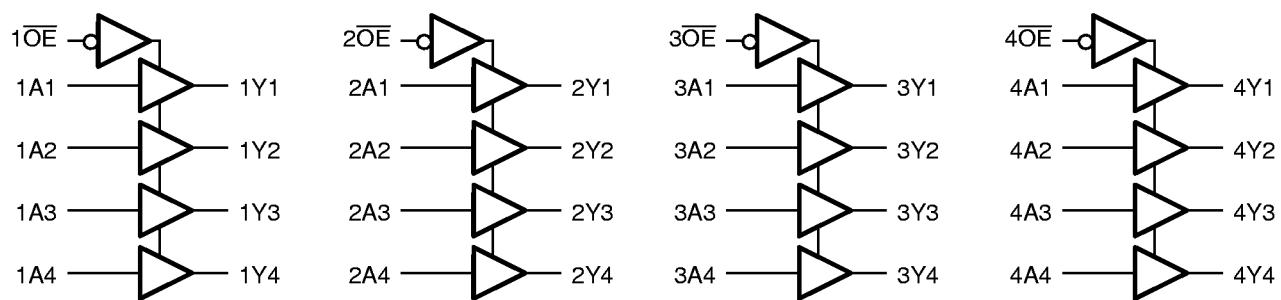
FEATURES/BENEFITS

- 5V tolerant inputs and outputs
- $10\mu A$ I_{CCQ} quiescent power supply current
- Hot insertable
- 2.0V-3.6V V_{CC} supply operation
- $\pm 24mA$ balanced output drive
- C speed performance: $t_{PD} = 4.1ns$
- Input hysteresis for noise immunity
- Meets or exceeds JEDEC Standard 36 specifications
- Multiple power and ground pins for low noise
- Operating temperature range:
 $-40^{\circ}C$ to $+85^{\circ}C$
- Latch-up performance exceeds 500mA
- ESD performance:
 Human body model > 2000V
 Machine model > 200V
- Packages available:
 48-pin TSSOP
 48-pin SSOP

DESCRIPTION

The QS74LCX16244 is a 16-bit bus interface buffer with three-state outputs that is ideal for driving address and data buses. Output enables are used to enable or disable Y ports by placing them in a high impedance condition. This device can be used as four 4-bit buffers, two 8-bit buffers, or a single 16-bit buffer. The 3.3V LCX family features low power, low switching noise, and fast switching speeds for low power portable applications as well as high-end, advanced workstation applications. 5V tolerant inputs and outputs allow this LCX product to be used in mixed 5V and 3.3V applications. Easy board layout is facilitated by the use of flow-through pinouts and byte enable controls provide architectural flexibility for systems designers. To accommodate hot-plug or live insertion applications, this product is designed not to load an active bus when V_{CC} is removed.

Figure 1. Functional Block Diagram



**Figure 2. Pin Configuration
(All Pins Top View)**

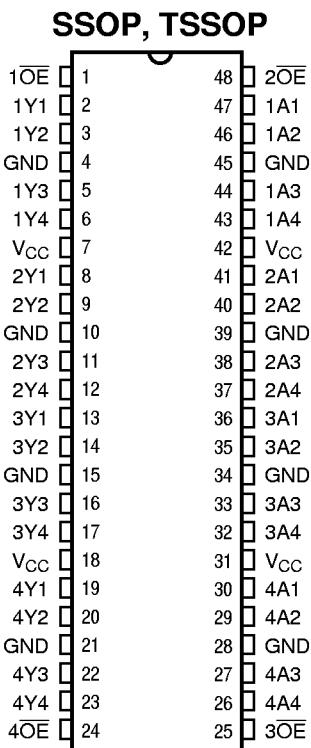


Table 1. Pin Description

Name	Description
x \overline{OE}	3-State Output Enable Inputs
xAx	Data Inputs
xYx	3-State Outputs

Table 2. Function Table

Inputs		Outputs
x \overline{OE}	xAx	xYx
L	L	L
L	H	H
H	X	Hi-Z

Table 3. Capacitance

Symbol	Pins	Typ	Unit	Conditions
C _{IN}	Input Capacitance	7.0	pF	V _{IN} = 0V, V _{OUT} = 0V, f = 1MHz
C _{I/O}	I/O Capacitance	8.0	pF	V _{IN} = 0V, V _{OUT} = 0V, f = 1MHz
C _{PD}	Power Dissipation Capacitance	20	pF	V _{CC} = 3.3V, V _{IN} = 0 or V _{CC} f = 10MHz

Note: Capacitance is characterized but not production tested.

Table 4. Absolute Maximum Ratings

Supply Voltage to Ground	-0.5V to +7.0V
DC Output Voltage V _{OUT}	
Outputs HIGH-Z	-0.5V to +7.0V
Outputs Active	-0.5V to V _{CC} + 0.5V
DC Input Voltage V _{IN}	-0.5V to 7.0V
DC Input Diode Current with V _{IN} < 0	-50mA
DC Output Diode Current	
V _O < 0	-50mA
V _O > V _{CC}	+50mA
DC Output Source/Sink Current (I _{OH} /I _{OL})	±50mA
DC Supply Current per Supply Pin	±100mA
DC Ground Current per Ground Pin	±100mA
T _{STG} Storage Temperature	-65°C to +150°C

Note: Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to this device resulting in functional or reliability type failures.

Table 5. Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage, Operating	2.0	3.6	V
V_{IN}	Input Voltage	0	5.5	V
V_{OUT}	Output Voltage in Active State	0	V_{CC}	V
V_{OUT}	Output Voltage in "OFF" State	0	5.5	V
I_{OH}/I_{OL}	Output Current $V_{CC} = 3.0 - 3.6V$ $V_{CC} = 2.7V$	—	± 24 ± 12	mA
$\Delta t/\Delta V$	Input Transition Slew Rate	—	10	ns/V
T_A	Operating Free Air Temperature	-40	+85	°C

Table 6. DC Electrical Characteristics Over Operating RangeIndustrial Temperature Range, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$

Symbol	Parameter	Test Conditions ⁽¹⁾	Min	Typ ⁽²⁾	Max	Unit
V_{IH}	Input HIGH Voltage	Logic HIGH for All Inputs	2.0	—	—	V
V_{IL}	Input LOW Voltage	Logic LOW for All Inputs	—	—	0.8	V
V_{OH}	Output HIGH Voltage	$V_{CC} = 2.7V, I_{OH} = -100\mu\text{A}$ $V_{CC} = 2.7V, I_{OH} = -12\text{mA}$ $V_{CC} = 3.0V, I_{OH} = -18\text{mA}$ $V_{CC} = 3.0V, I_{OH} = -24\text{mA}$	$V_{CC} = 0.2$ 2.2 2.4 2.2	— — — —	— — — —	V
V_{OL}	Output LOW Voltage	$V_{CC} = 2.7V, I_{OL} = 100\mu\text{A}$ $V_{CC} = 2.7V, I_{OL} = 12\text{mA}$ $V_{CC} = 3.0V, I_{OL} = 16\text{mA}$ $V_{CC} = 3.0V, I_{OL} = 24\text{mA}$	— — — —	— — — —	0.2 0.4 0.4 0.5	V
ΔV_T	Input Hysteresis ⁽³⁾	$V_{TLH} - V_{THL}$ for All Inputs	—	150	—	mV
I_I	Input Leakage Current	$V_I = 0V, V_I = 5.5V, V_{CC} = 3.6V$	—	—	± 1.0	μA
I_{OZ}	High-Z I/O Leakage	$V_O = 0V, V_O = 5.5V$ $V_I = V_{IH}$ or $V_{IL}, V_{CC} = 3.6V$	—	—	± 1.0	μA
I_{OS}	Short Circuit Current ^(3,4)	$V_{CC} = 3.6V, V_O = \text{GND}$	-60	—	-240	mA
I_{OFF}	Power Off Leakage	$V_{CC} = 0V, V_I$ or $V_O = 5.5V$	—	—	10	μA
V_{IK}	Input Clamp Voltage	$V_{CC} = 2.7V, I_{IN} = -18\text{mA}$	—	-0.7	-1.2	V

Notes:

- For conditions shown as Max or Min use appropriate value specified under Recommended Operating Conditions for the applicable device type.
- Typical values are at $V_{CC} = 3.3V$, and $T_A = 25^\circ\text{C}$.
- These parameters are guaranteed by characterization, but not production tested.
- Not more than one output should be tested at one time. Duration of test should not exceed one second.

Table 7. Power Supply Characteristics

Symbol	Parameter	Test Conditions ⁽¹⁾	Typ ⁽²⁾	Max	Unit
I _{CC}	Quiescent Power Supply Current	V _{CC} = 3.6V, Freq = 0 V _{IN} = GND or V _{CC}	0.1	10	µA
ΔI _{CC}	Supply Current per Input @ TTL HIGH	V _{CC} = 3.6V, V _{IN} = V _{CC} -0.6V ⁽³⁾	2.0	30	µA
I _{CCD}	Supply Current per Input per MHz ⁽⁴⁾	V _{CC} = 3.6V, Outputs Open One Bit Toggling @ 50% Duty Cycle xOĒ = GND	50	75	µA/MHz
I _C	Total Power Supply Current ⁽⁶⁾	V _{CC} = 3.6V, Outputs Open One Bit Toggling @ 50% Duty Cycle xOĒ = GND, f _I = 10MHz	V _{IN} = V _{CC} -0.6V V _{IN} = GND	0.5 ⁽⁵⁾	0.8 ⁽⁵⁾
		V _{CC} = 3.6V, Outputs Open Sixteen Bits Toggling @ 50% Duty Cycle xOĒ = GND, f _I = 2.5MHz	V _{IN} = V _{CC} -0.6V V _{IN} = GND	2.0 ⁽⁵⁾	3.3 ⁽⁵⁾

Notes:

1. For conditions shown as Min. or Max., use the appropriate values specified under Recommended Operating Conditions for applicable device type.

2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

3. Per TTL driven input. All Other Inputs at V_{CC} or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed by design but not tested.

6. I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}.

$$I_C = I_{CCQ} + \Delta I_{CC} D_H N_T + I_{CCD} f N_O$$

I_{CCQ} = Quiescent Current (I_{CCL}, I_{CCH}, and I_{CCZ}).

ΔI_{CC} = Power Supply Current for a TTL-High Input (V_{IN} = V_{CC}-0.6V).

D_H = Duty Cycle for TTL High Inputs.

N_T = Number of TTL High Inputs.

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL).

f = Average Switching Frequency per Output.

N_O = Number of Outputs Switching

Table 8. Dynamic Switching Characteristics⁽¹⁾

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C	Units
				Typical	
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	C _L = 50pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	C _L = 50pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V

Note:

1. Characterized but not production tested.

Table 9. Switching Characteristics Over Operating RangeIndustrial Temperature Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$. $C_{\text{LOAD}} = 50 \text{ pF}$, $R_{\text{LOAD}} = 500\Omega$ unless otherwise noted.

Symbol	Description ⁽¹⁾	16244				16244C		Unit	
		$V_{\text{CC}} = 3.3 \pm 0.3\text{V}$		$V_{\text{CC}} = 2.7\text{V}^{(2)}$		$V_{\text{CC}} = 3.3 \pm 0.3\text{V}$			
		Min	Max	Min	Max	Min	Max		
t_{PHL}	Propagation Delay xAx to xYx	1.5	4.5	1.5	5.2	1.5	4.1	ns	
t_{PLH}									
t_{PZH}	Output Enable Time $x\overline{OE}$ to xYx	1.5	5.5	1.5	6.3	1.5	5.5	ns	
t_{PZL}									
t_{PHZ}	Output Disable Time ⁽²⁾ $x\overline{OE}$ to xYx	1.5	5.4	1.5	5.7	1.5	5.2	ns	
t_{PLZ}									
$t_{\text{SK(O)}}$	Output Skew ⁽³⁾	—	0.5	—	—	—	0.5	ns	

Notes:

1. Minimums guaranteed but not tested. See Test Circuit and Waveforms.
2. Guaranteed by characterization.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by characterization but not production tested.

TEST CIRCUIT AND WAVEFORMS

Figure 3. Test Circuit

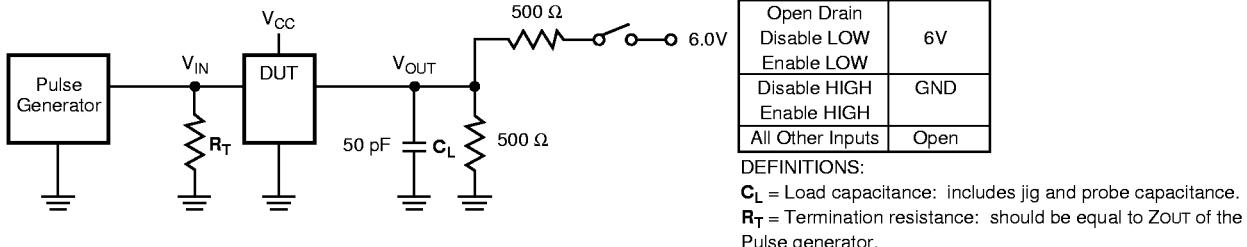


Figure 4. Setup, Hold, and Release Timing

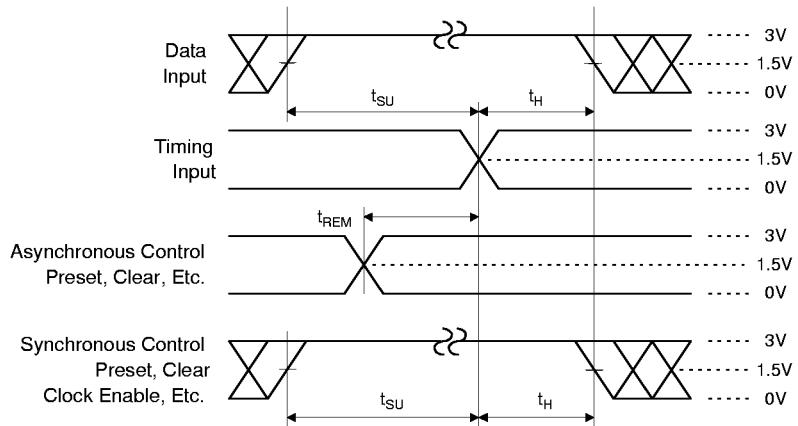
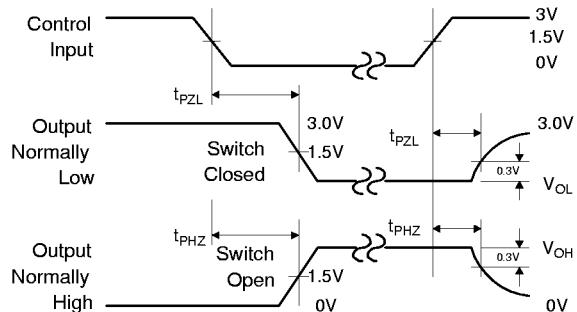
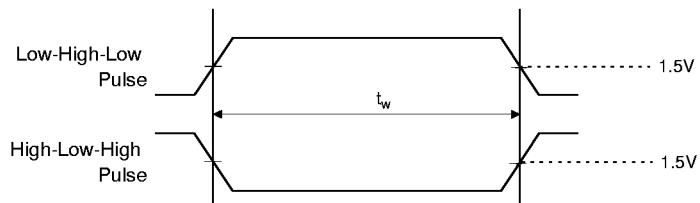
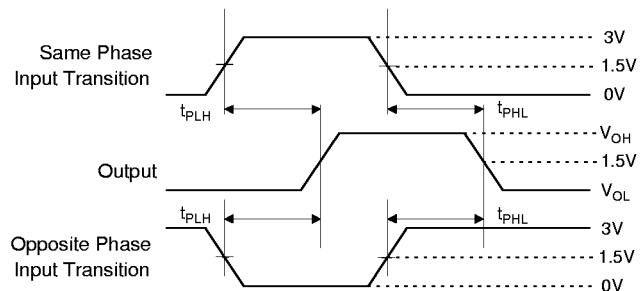
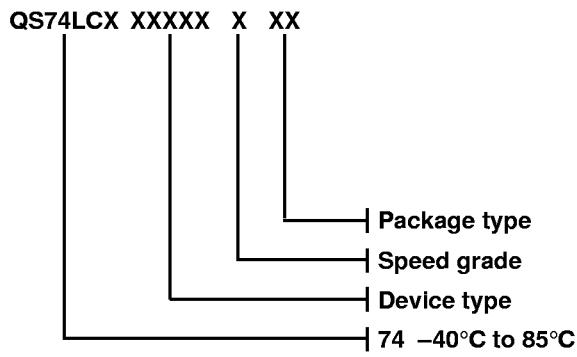


Figure 5. Enable and Disable Timing



Notes:

1. Input Control Enable = LOW and input Control Disable = HIGH.
2. Pulse Generator for All Pulses: Rate ≤ 1.0 MHz;
 $Z_{OUT} \leq 50\Omega$; $t_F, t_R \leq 2.5$ ns.

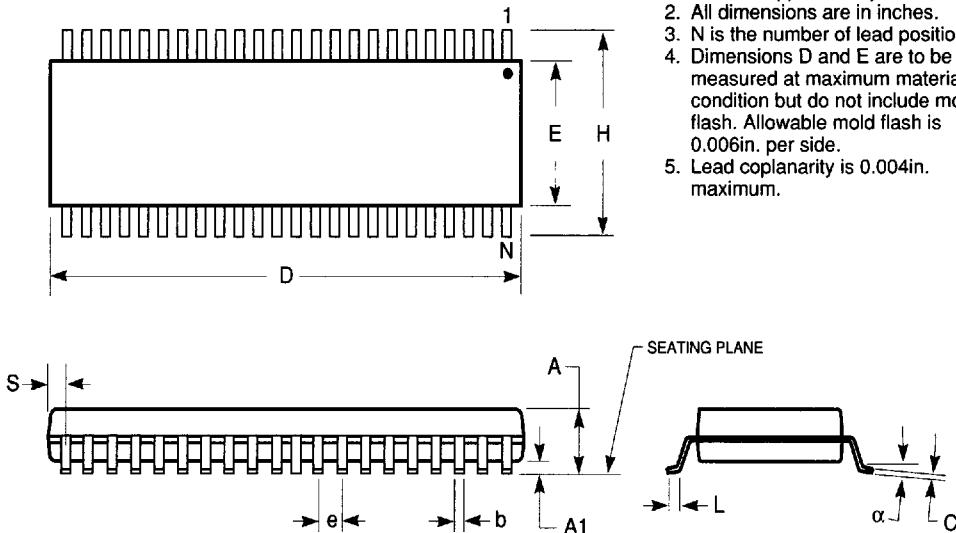
Figure 6. Pulse Width**Figure 7. Propagation Delay****ORDERING INFORMATION****Device Type:**

16244

Speed Grades:Blank – Standard
C**Package Type:**PV – SSOP, 300 mil
PA – TSSOP, 240 mil

300-MIL SSOP - Package Code PV

**Shrink Small Outline Package
Plastic Small Outline Gull-Wing**



Notes:

1. Refer to applicable symbol list.
2. All dimensions are in inches.
3. N is the number of lead positions.
4. Dimensions D and E are to be measured at maximum material condition but do not include mold flash. Allowable mold flash is 0.006in. per side.
5. Lead coplanarity is 0.004in. maximum.

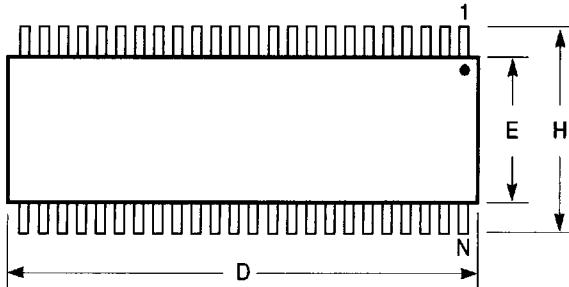
JEDEC#		MO-118AA			MO-118AB		
DWG#		PSS-48B			PSS-56B		
Symbol		Min	Nom	Max	Min	Nom	Max
A		0.095	0.102	0.110	0.095	0.102	0.110
A1		0.008	0.012	0.016	0.008	0.012	0.016
b		0.008	0.010	0.0135	0.008	0.010	0.0135
C		0.005	0.008	0.010	0.005	0.008	0.010
D		0.620	0.625	0.630	0.720	0.725	0.730
E		0.291	0.295	0.299	0.291	0.295	0.299
e		0.025 BSC			0.025 BSC		
H		0.395	0.410	0.420	0.395	0.410	0.420
L		0.020	0.030	0.040	0.020	0.030	0.040
N		48			56		
α		0°	5°	8°	0°	5°	8°
S		0.022	0.025	0.028	0.022	0.025	0.028

7466803 0003755 104

QUALITY SEMICONDUCTOR, INC.

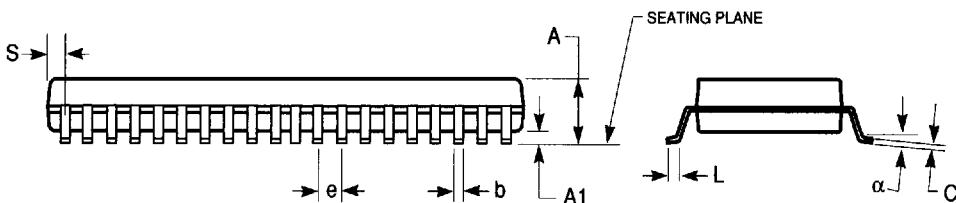
240-MIL TSSOP - Package Code PA

Thin Shrink Small Outline Package
Plastic Small Outline Gull-Wing



Notes:

1. Refer to applicable symbol list.
2. N is the number of lead positions.
3. Dimensions D, E, and S are to be measured at maximum material condition but do not include mold flash. Allowable mold flash is 0.006 in. per side.
4. Lead coplanarity is 0.004 in. maximum.



JEDEC#	MO-153ED			MO-153EE			MO-153ED			MO-153EE		
DWG#	PSS-48C			PSS-56C			PSS-48C			PSS-56C		
Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
A	0.039	0.043	0.047	0.039	0.043	0.047	1.00	1.10	1.20	1.00	1.10	1.20
A1	0.002	0.004	0.006	0.002	0.004	0.006	0.05	0.10	0.15	0.05	0.10	0.15
b	0.006	0.008	0.011	0.006	0.008	0.011	0.17	0.20	0.27	0.17	0.20	0.27
C	0.004	0.006	0.008	0.004	0.006	0.008	0.09	0.15	0.20	0.09	0.15	0.20
D	0.488	0.492	0.496	0.547	0.551	0.555	12.40	12.50	12.60	13.90	14.00	14.10
E	0.236	0.240	0.244	0.236	0.240	0.244	6.00	6.10	6.20	6.00	6.10	6.20
e	0.0197 BSC			0.0197 BSC			0.50 BSC			0.50 BSC		
H	0.315	0.319	0.323	0.315	0.319	0.323	8.00	8.10	8.20	8.00	8.10	8.20
L	0.018	0.024	0.030	0.018	0.024	0.030	0.45	0.60	0.75	0.45	0.60	0.75
N	48			56			48			56		
α	0°	5°	8°	0°	5°	8°	0°	5°	8°	0°	5°	8°
S	0.015	0.020	0.025	0.006	0.010	0.014	0.38	0.50	0.65	0.15	0.25	0.35

DIMENSIONS IN INCHES

DIMENSIONS IN MILLIMETERS

■ 7466803 0003757 T87 ■

QUALITY SEMICONDUCTOR, INC.